

**IN THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently amended) A light emitting device comprising:
  - a substrate having an insulating surface;
  - a thin film transistor formed over the substrate;
  - an insulating film formed over the thin film transistor;
  - a first electrode formed over the insulating film and connected to the thin film transistor through the insulating film;
  - a partition wall covering an edge of the first electrode and formed over the insulating film;
  - a layer comprising an organic compound formed over and in contact with the first electrode; and
    - a second electrode in contact with the layer comprising an organic compound, wherein the partition wall comprises a laminate of an organic resin layer and a light-absorbing layer, wherein the organic resin layer comprises a top surface and a side surface, the side surface being tapered, wherein the light absorbing layer entirely covers the top surface of the organic resin layer, and wherein the layer comprising an organic compound is in contact with the side surface of the organic resin layer.

2. (Previously presented) A light emitting device according to claim 1, wherein the partition wall covers other regions than a light emitting region in which the first electrode and the organic

compound-containing layer are in contact with each other.

3. (Previously Presented) A light emitting device according to claim 1, wherein the light-absorbing layer includes at least one layer comprising a material selected from the group consisting of Al<sub>2</sub>O<sub>3</sub>, SiO<sub>2</sub>, ZrO<sub>2</sub>, HfO<sub>2</sub>, Sc<sub>2</sub>O<sub>3</sub>, TiO<sub>2</sub>, ITO and ZnO.

4. (Previously presented) A light emitting device according to claim 1, wherein the light-absorbing layer includes at least a light-transmissive insulating film comprising nitride.

5. (Previously presented) A light emitting device according to claim 1, wherein the light-absorbing layer includes at least a layer comprising a material selected from the group consisting of Al, Cu, Au, Mo, Ni, Pt, Rh, Ag, W, Cr, Co, Si, Zr, Ta, Inconel and Nichrome.

6. (Canceled).

7. (Previously Presented) A light emitting device according to claim 1, wherein the light-absorbing layer comprises a laminate of a metal film mainly composed of aluminum, a silicon nitride film, a titanium nitride film, and another silicon nitride film.

8. (Original) A light emitting device according to claim 1, wherein the second electrode is a conductive film transmissive of light.

9. (Original) A light emitting device according to claim 1, wherein the first electrode has a

concave shape and is formed in a self-aligning manner using the partition wall as a mask.

10. (Original) A light emitting device according to claim 1, wherein the first electrode is an anode and the second electrode is a cathode.

11. (Original) A light emitting device according to claim 1, wherein the first electrode is a cathode and the second electrode is an anode.

12. (Original) A light emitting device according to claim 1, wherein the layer comprising an organic compound is made of a material emitting red light, green light, or blue light.

13. (Original) A light emitting device according to claim 1, wherein the layer comprising an organic compound comprises a material emitting white light, and is combined with a color filter provided in a sealing member.

14. (Original) A light emitting device according to claim 1, wherein the layer comprising an organic compound comprises a material emitting monochromatic light, and is combined with one of a color conversion layer and a colored layer provided in a sealing member.

15. (Original) A light emitting device according to claim 1, wherein the light emitting device is any one of a video camera, a digital camera, a goggle-type display, a car navigation system, a personal computer, a DVD player, an electronic game machine, and a portable information terminal.

16-22. (Canceled)

23. (Currently amended) A light emitting device comprising:

a substrate having an insulating surface;

a thin film transistor formed over the substrate;

an insulating film formed over the thin film transistor;

a first electrode formed over the insulating film and connected to the thin film transistor through the insulating film;

a partition wall covering an edge of the first electrode and formed over the insulating film;

a layer comprising an organic compound formed over and in contact with the first electrode;

and

a second electrode in contact with the layer comprising an organic compound,

wherein the partition wall comprises a laminate of an organic resin layer and a light-absorbing multilayer film including three layers formed of different materials,

wherein the organic resin layer comprises a top surface and a side surface, the side surface being tapered,

wherein the light absorbing multilayer film entirely covers the top surface of the organic resin layer, and

wherein the layer comprising an organic compound is in contact with the side surface of the organic resin layer.

24. (Previously presented) A light emitting device according to claim 23, wherein the partition wall covers other regions than a light emitting region in which the first electrode and the

organic compound-containing layer are in contact with each other.

25. (Previously presented) A light emitting device according to claim 23, wherein the light-absorbing multilayer film includes at least one layer comprising a material selected from the group consisting of  $\text{Al}_2\text{O}_3$ ,  $\text{SiO}_2$ ,  $\text{ZrO}_2$ ,  $\text{HfO}_2$ ,  $\text{Sc}_2\text{O}_3$ ,  $\text{TiO}_2$ , ITO and  $\text{ZnO}$ .

26. (Previously presented) A light emitting device according to claim 23, wherein the light-absorbing multilayer film includes at least a light-transmissive insulating film comprising nitride.

27. (Previously presented) A light emitting device according to claim 23, wherein the light-absorbing multilayer film includes at least a layer comprising a material selected from the group consisting of Al, Cu, Au, Mo, Ni, Pt, Rh, Ag, W, Cr, Co, Si, Zr, Ta, Inconel and Nichrome.

28. (Previously presented) A light emitting device according to claim 23, wherein the light-absorbing multilayer film comprises a laminate of a metal film mainly composed of aluminum, a silicon nitride film, a titanium nitride film, and another silicon nitride film, stacked in this order.

29. (Previously presented) A light emitting device according to claim 23, wherein the second electrode is a conductive film transmissive of light.

30. (Previously presented) A light emitting device according to claim 23, wherein the first electrode has a concave shape and is formed in a self-aligning manner using the partition wall as a mask.

31. (Previously presented) A light emitting device according to claim 23, wherein the first electrode is an anode and the second electrode is a cathode.

32. (Previously presented) A light emitting device according to claim 23, wherein the first electrode is a cathode and the second electrode is an anode.

33. (Previously presented) A light emitting device according to claim 23, wherein the layer comprising an organic compound is made of a material emitting red light, green light, or blue light.

34. (Previously presented) A light emitting device according to claim 23, wherein the layer comprising an organic compound comprises a material emitting white light, and is combined with a color filter provided in a sealing member.

35. (Previously presented) A light emitting device according to claim 23, wherein the layer comprising an organic compound comprises a material emitting monochromatic light, and is combined with one of a color conversion layer and a colored layer provided in a sealing member.

36. (Previously presented) A light emitting device according to claim 23, wherein the light emitting device is any one of a video camera, a digital camera, a goggle-type display, a car navigation system, a personal computer, a DVD player, an electronic game machine, and a portable information terminal.

37. (Previously presented) A light emitting device comprising:

a first electrode connected to a thin film transistor over a substrate having an insulating surface;

a partition wall covering an edge of the first electrode;

a layer comprising an organic compound in contact with the first electrode; and

a second electrode in contact with the layer comprising an organic compound,

wherein the partition wall comprises a laminate of an organic resin layer and a light-absorbing multilayer film including a reflective metal film, a first light transmissive insulating film comprising nitride, a metal nitride film and a second light-transmissive insulating film comprising nitride.

38. (Previously presented) A light emitting device according to claim 37, wherein the partition wall covers other regions than a light emitting region in which the first electrode and the organic compound-containing layer are in contact with each other.

39. (Previously presented) A light emitting device according to claim 37, wherein the light-absorbing multilayer film includes at least one layer comprising a material selected from the group consisting of  $\text{Al}_2\text{O}_3$ ,  $\text{SiO}_2$ ,  $\text{ZrO}_2$ ,  $\text{HfO}_2$ ,  $\text{Sc}_2\text{O}_3$ ,  $\text{TiO}_2$ , ITO and  $\text{ZnO}$ .

40. (Previously presented) A light emitting device according to claim 37, wherein the light-absorbing multilayer film includes at least a layer comprising a material selected from the group consisting of Al, Cu, Au, Mo, Ni, Pt, Rh, Ag, W, Cr, Co, Si, Zr, Ta, Inconel and Nichrome.

41. (Previously presented) A light emitting device according to claim 37, wherein the

reflective metal film is mainly composed of aluminum.

42. (Canceled)

43. (Previously presented) A light emitting device according to claim 37, wherein at least one of the first and second light transmissive insulating films is a silicon nitride film.

44. (Previously presented) A light emitting device according to claim 37, wherein the metal nitride film is a titanium nitride film.

45. (Previously presented) A light emitting device according to claim 37, wherein the second electrode is a conductive film transmissive of light.

46. (Previously presented) A light emitting device according to claim 37, wherein the first electrode has a concave shape and is formed in a self-aligning manner using the partition wall as a mask.

47. (Previously presented) A light emitting device according to claim 37, wherein the first electrode is an anode and the second electrode is a cathode.

48. (Previously presented) A light emitting device according to claim 37, wherein the first electrode is a cathode and the second electrode is an anode.

49. (Previously presented) A light emitting device according to claim 37, wherein the layer comprising an organic compound is made of a material emitting red light, green light, or blue light.

50. (Previously presented) A light emitting device according to claim 37, wherein the layer comprising an organic compound comprises a material emitting white light, and is combined with a color filter provided in a sealing member.

51. (Previously presented) A light emitting device according to claim 37, wherein the layer comprising an organic compound comprises a material emitting monochromatic light, and is combined with one of a color conversion layer and a colored layer provided in a sealing member.

52. (Previously presented) A light emitting device according to claim 37, wherein the light emitting device is any one of a video camera, a digital camera, a goggle-type display, a car navigation system, a personal computer, a DVD player, an electronic game machine, and a portable information terminal.

53. (Currently amended) A light emitting device comprising:

- a substrate having an insulating surface;
- a thin film transistor formed over the substrate;
- an insulating film formed over the thin film transistor;
- a first electrode formed over and in contact with the insulating film and connected to the thin film transistor through the insulating film;
- a partition wall covering an edge of the first electrode and formed over the insulating film;

a layer comprising an organic compound formed over and in contact with the first electrode;  
and

a second electrode in contact with the layer comprising an organic compound,  
wherein the partition wall comprises a laminate of an organic resin layer and a light-absorbing multilayer film,

wherein the organic resin layer comprises a top surface and a side surface, the side surface being tapered,

wherein the light absorbing multilayer film entirely covers the top surface of the organic resin layer, and

wherein the layer comprising an organic compound is in contact with the side surface of the organic resin layer.

54. (Previously presented) A light emitting device according to claim 53, wherein the partition wall covers other regions than a light emitting region in which the first electrode and the organic compound-containing layer are in contact with each other.

55. (Previously presented) A light emitting device according to claim 53, wherein the light-absorbing multilayer film includes at least one layer comprising a material selected from the group consisting of  $\text{Al}_2\text{O}_3$ ,  $\text{SiO}_2$ ,  $\text{ZrO}_2$ ,  $\text{HfO}_2$ ,  $\text{Sc}_2\text{O}_3$ ,  $\text{TiO}_2$ , ITO and  $\text{ZnO}$ .

56. (Previously presented) A light emitting device according to claim 53, wherein the light-absorbing multilayer film includes at least a light-transmissive insulating film comprising nitride.

57. (Previously presented) A light emitting device according to claim 53, wherein the light-absorbing multilayer film includes at least a layer comprising a material selected from the group consisting of Al, Cu, Au, Mo, Ni, Pt, Rh, Ag, W, Cr, Co, Si, Zr, Ta, Inconel and Nichrome.

58. (Previously presented) A light emitting device according to claim 53, wherein the light-absorbing multilayer film comprises a laminate of a metal film mainly composed of aluminum, a silicon nitride film, a titanium nitride film, and another silicon nitride film.

59. (Previously presented) A light emitting device according to claim 53, wherein the second electrode is a conductive film transmissive of light.

60. (Previously presented) A light emitting device according to claim 53, wherein the first electrode has a concave shape and is formed in a self-aligning manner using the partition wall as a mask.

61. (Previously presented) A light emitting device according to claim 53, wherein the first electrode is an anode and the second electrode is a cathode.

62. (Previously presented) A light emitting device according to claim 53, wherein the first electrode is a cathode and the second electrode is an anode.

63. (Previously presented) A light emitting device according to claim 53, wherein the layer comprising an organic compound is made of a material emitting red light, green light, or blue light.

64. (Previously presented) A light emitting device according to claim 53, wherein the layer comprising an organic compound comprises a material emitting white light, and is combined with a color filter provided in a sealing member.

65. (Previously presented) A light emitting device according to claim 53, wherein the layer comprising an organic compound comprises a material emitting monochromatic light, and is combined with one of a color conversion layer and a colored layer provided in a sealing member.

66. (Previously presented) A light emitting device according to claim 53, wherein the light emitting device is any one of a video camera, a digital camera, a goggle-type display, a car navigation system, a personal computer, a DVD player, an electronic game machine, and a portable information terminal.

67. (Previously presented) A light emitting device according to claim 1, wherein the first electrode comprises at least two layers.

68. (Previously presented) A light emitting device according to claim 23, wherein the first electrode comprises at least two layers.

69. (Previously presented) A light emitting device according to claim 37, wherein the first electrode comprises at least two layers.

70. (Previously presented) A light emitting device according to claim 53, wherein the first

electrode comprises at least two layers.